

STLVDS051

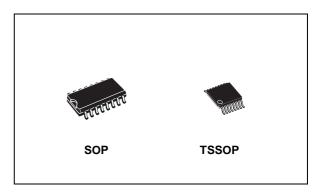
HIGH SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

- MEETS OR EXCEED THE REQUIREMENTS OF ANSI EIA/TIA-644-1995 STANDARD
- SIGNALING RATES UP TO 400Mbit/s
- BUS TERMINAL ESD EXCEEDS 6KV
- OPERATES FROM A SINGLE 3.3V SUPPLY
- LOW-VOLTAGE DIFFERENTIAL SIGNALING WITH TYPICAL OUTPUT VOLTAGE OF 350mV AND A 100Ω LOAD
- PROPAGATION DELAY TIMES: DRIVER: 2ns (TYP) RECEIVER: 3ns (TYP)
- POWER DISSIPATION AT 200MHz: DRIVER: 25mW (TYP) RECEIVER: 60mW (TYP)
- LVTTL INPUT LEVELS ARE 5V TOLERANT
- RECEIVER HAS OPEN-CIRUIT FAIL-SAFE

DESCRIPTION

The STLVDS051 is differential line drivers and receivers that use low-voltage differential signaling (LVDS) to achieve signaling rate as high as 400Mbps.

The EIA/TIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247 mV into a 100 Ω load and receipt of 100 mV signals with up to 1 V of



ground potential difference between a transmitter and receiver.

The intended application of this device an signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately 100 Ω characteristic impedance.

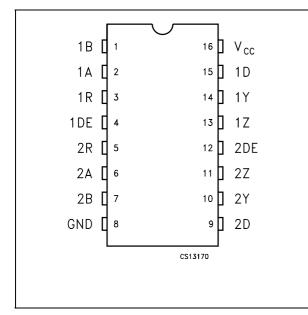
The transmission media may be printed-circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application specific characteristics).

ORDERING CODES

Туре	Temperature Range	Package	Comments
STLVDS051BD	-40 to 85 °C	SO-16 (Tube)	50 parts per tube / 20 tube per box
STLVDS051BDR	-40 to 85 °C	SO-16 (Tape & Reel)	2500 parts per reel
STLVDS051BTR	-40 to 85 °C	TSSOP16 (Tape & Reel)	2500 parts per reel

STLVDS051

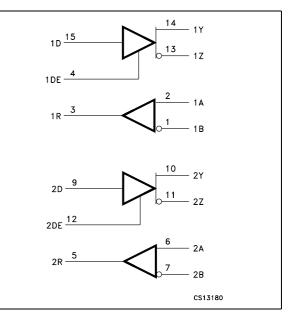
PIN CONFIGURATION



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
1,2, 6, 7	1A, 1B, 2A, 2B	Receiver Inputs
3, 5	1R, 2R	Receiver Outputs
4, 12	1DE, 2DE	Driver Enable
9, 15	2D, 1D	Driver Inputs
10, 11, 13, 14	2Y, 2Z, 1Y, 1Z	Driver Outputs
8	GND	Ground
16	V _{CC}	Supply Voltage

FUNCTIONAL DIAGRAM



TRUTH TABLE FOR RECEIVER

V _{ID} =V _A -V _B	R
$V_{ID} \ge 100 mV$	Н
-100mV < V _{ID} < 100mV	?
$V_{ID} \leq -100 mV$	L
OPEN	Н

TRUTH TABLE FOR DRIVER

D	DE	Y	Z
L	Н	L	Н
Н	Н	Н	L
OPEN	Н	L	Н
Х	L	Z	Z

L=Low level, H=High Level, X=Don't care, Z= High Impedance

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage		-0.5 to 4	V
VI	Voltage Range	D, R, DE	-0.5 to 6	V
ESD	ESD Protection Voltage (HBM)	Y, Z, A, B, and GND	± 6	кv
		All Pins	± 3	ΓV
T _{stg}	Storage Temperature Range		-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{CC}	Supply Voltage	3.0	3.3	3.6	V
V _{IH}	HIGH Level Input Voltage	2.0			V
V _{IL}	LOW Level Input Voltage			0.8	V
V _{ID}	Magnitude Of Differential Input Voltage	0.1		0.6	V
V _{IC}	Common Mode Input Voltage	V _{ID} /2		24- V _{ID} /2	V
				V _{CC} -0.8	
T _A	Operating Temperature Range	-40		85	°C

ELECTRICAL CHARACTERISTICS (Typical values are at $T_A = 25^{\circ}$ C, $V_{CC} = 3.3$ V ±10%, $T_A = -40$ to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CC}	Supply Current	Drivers enabled, No Receivers load, Driver R_L =100 Ω		12	20	mA
		Drivers Disabled, No load		4	6	

DRIVER ELECTRICAL CHARACTERISTICS (Typical values are at $T_A = 25^{\circ}$ C, $V_{CC} = 3.3$ V ±10%,

Symbol	Parameter	Test Conditio	ons	Min.	Тур.	Max.	Unit
V _{OD}	Differential Output Voltage Magnitude	R _L = 100Ω		247	340	454	mV
$\Delta V_{OD} $	Change in Differential Output Voltage Magnitude Between Logic States	R _L = 100Ω		-50		50	mV
$\Delta V_{OC(SS)}$	Change in Steady-state Common Mode Output Voltage Between Logic States			-50		50	mV
V _{OC(SS)}	Steady-state Common Mode Output Voltage			1.125	1.2	1.375	V
V _{OC(PP)}	Peak to Peak Common mode Output Voltage				50	150	mV
I _{IH}	High Level Input Current	V _{IH} = 5V	DE		-0.5	-20	μA
			D		2	20	μΑ
١ _{IL}	Low Level Input Current	$V_{IL} = 0.8V$	DE		-0.5	-10	μΑ
			D		1	10	μΑ
I _{OS}	Short Circuit Output Current	$V_{O(Y)}$ or $V_{O(Z)} = 0V$			6	10	mA
		$V_{OD} = 0$			4	10	mA
I _{OZ}	High Impedance Output	V _O = 600mV				± 1	μΑ
	Current	$V_{O} = 0V \text{ or } V_{CC}$				± 1	μA
I _{O(OFF)}	Power OFF Output Current	$V_{CC} = 0V$ $V_O = 3.6V$				± 1	μA
C _{IN}	Input Capacitance				3		pF

 $T_A = -40$ to 85°C unless otherwise specified)

RECEIVER ELECTRICAL CHARACTERISTICS (Typical values are at $T_A = 25$ °C, $V_{CC} = 3.3V \pm 10\%$, $T_A = -40$ to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{ITH+}	Positive-going Differential Input Voltage Threshold				100	mV
V _{ITH-}	Negative-going Differential Input Voltage Threshold		-100			mV
V _{OH}	High Level Output Voltage	I _{OH} = -8mA	2.4			V
V _{OL}	Low Level Output Voltage	I _{OL} = 2mA			0.4	V
l _l	Input Current (A or B Inputs)	V _I =0V	-2	-11	-20	μA
		$V_{I} = 2.4V$	-1	-3		μA
I _{I(OFF)}	Power OFF Input Current (A or B Inputs)	V _{CC} = 0V			±20	μA
IIH	High Level Input Current (Enable)	V _{IH} = 5V			±10	μA
Ι _{ΙL}	Low Level Input Current (Enable)	$V_{IL} = 0.8V$			±10	μA
I _{OZ}	High Impedance Output Current	V _O = 0 or 5V			± 10	μA
C _{IN}	Input Capacitance			3		pF

DRIVER SWITCHING CHARACTERISTICS (Typical values are at $T_A = 25$ °C, $V_{CC} = 3.3V \pm 10\%$, $T_A = -40$ to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{PLH}	Propagation Delay Time, Low to High Output	$R_L = 100\Omega$ $C_L = 10pF$		2	2.7	ns
t _{PHL}	Propagation Delay Time, High to Low Output			2	2.7	ns
t _r	Differential Output Signal Rise Time			0.4	1	ns
t _f	Differential Output Signal Fall Time			0.4	1	ns
t _{sk(P)}	Pulse Skew (t _{THL} - t _{TLH}) (note1)			50		ps
t _{sk(O)}	Channel-to-channel Output Skew (note2)			40		ps
t _{PZH}	Propagation Delay Time, High Impedance to High Level Output			6	10	ns
t _{PZL}	Propagation Delay Time, High Impedance to Low Level Output			6	10	ns
t _{PHZ}	Propagation Delay Time, High Level to High Impedance Output			3	10	ns
t _{PLZ}	Propagation Delay Time, Low Level to High Impedance Output			3	10	ns

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RECEIVER SWITCHING CHARACTERISTICS (Typical values are at $T_A = 25$ °C, $V_{CC} = 3.3V \pm 10\%$, $T_A = -40$ to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{PLH}	Propagation Delay Time, Low to High Output	C _L = 10pF		3.0	4.0	ns
t _{PHL}	Propagation Delay Time, High to Low Output			3.0	4.0	ns
t _r	Differential Output Signal Rise Time			0.6	1	ns
t _f	Differential Output Signal Fall Time			0.6	1	ns
t _{sk(P)}	Pulse Skew (t _{THL} - t _{TLH}) (Note 1)			0.25		ns
t _{PZH}	Propagation Delay Time, High Impedance to High Level Output			2.5		ns
t _{PZL}	Propagation Delay Time, High Impedance to Low Level Output			2.5		ns
t _{PHZ}	Propagation Delay Time, High Level to High Impedance Output			7		ns
t _{PLZ}	Propagation Delay Time, Low Level to High Impedance Output			4		ns

Note 1: $t_{sk(P)}$ is the magnitude of the time difference between the high to low and low to high propagation delay times at an output Note 2: $t_{sk(O)}$ is the magnitude of the time difference between the output of a single device with all their inputs connected together. Note 3: $t_{sk(PP)}$ is the magnitude of the difference between any specified terminals of two devices when both devices operate with the same supply voltages, same temperature, and have identical packages and test circuit.

TYPICAL PERFORMANCE CHARACTERISTICS (unless otherwise specified $T_J = 25^{\circ}C$)

Figure 1 : Output Current vs Output High Voltage for Receiver

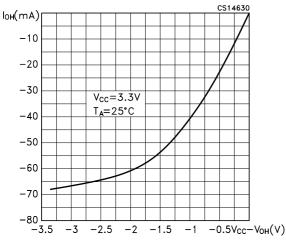
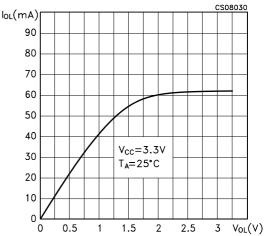
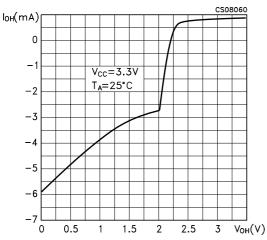


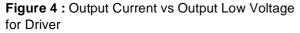
Figure 2 : Output Current vs Output Low Voltage for Receiver

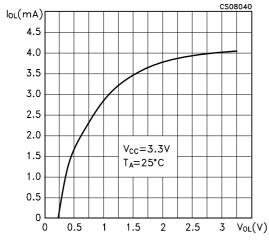


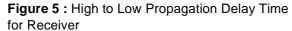
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Figure 3 : Output Current vs Output High Voltage for Driver









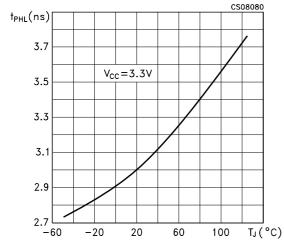


Figure 6 : Low to High Propagation Delay Time for Receiver

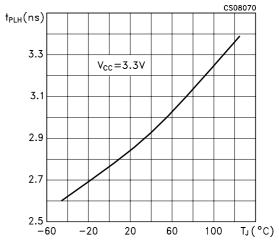
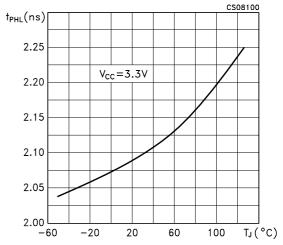
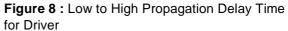
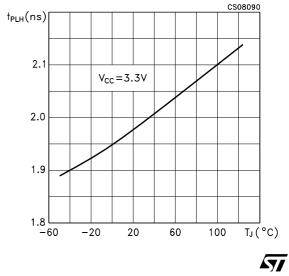


Figure 7 : High to Low Propagation Delay Time for Driver

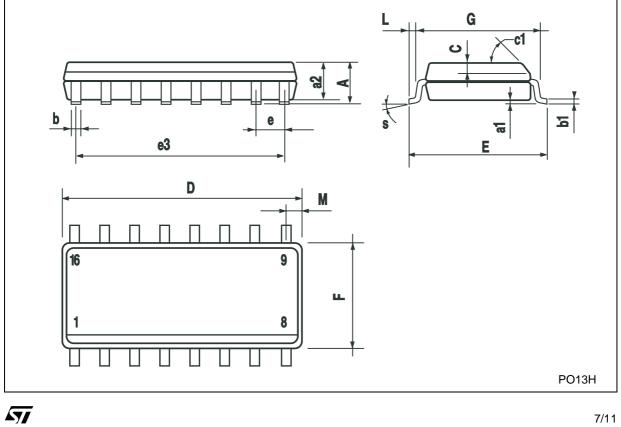






DIM.		mm.			inch	
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			1.75			0.068
a1	0.1		0.2	0.004		0.008
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)		•
D	9.8		10	0.385		0.393
Е	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024





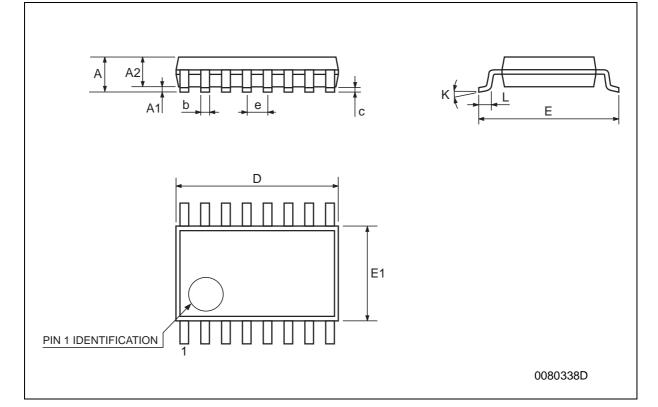
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DIM.	mm.			inch			
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			1.2			0.047	
A1	0.05		0.15	0.002	0.004	0.006	
A2	0.8	1	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.0079	
D	4.9	5	5.1	0.193	0.197	0.201	
E	6.2	6.4	6.6	0.244	0.252	0.260	
E1	4.3	4.4	4.48	0.169	0.173	0.176	
е		0.65 BSC			0.0256 BSC		
К	0°		8°	0°		8°	

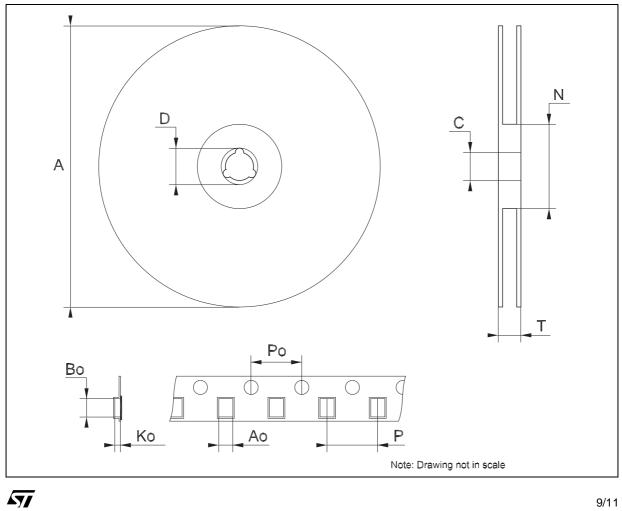




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DIM.	mm.			inch			
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	6.45		6.65	0.254		0.262	
Во	10.3		10.5	0.406		0.414	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	

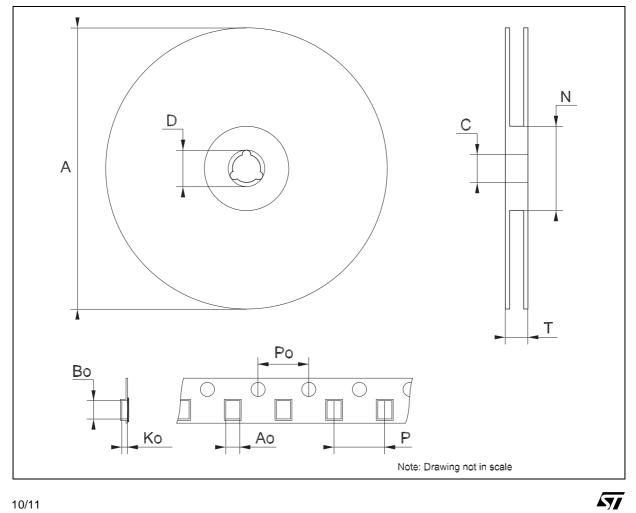




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	Tape & Reel TSSOP16 MECHANICAL DATA						
DIM	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	6.7		6.9	0.264		0.272	
Во	5.3		5.5	0.209		0.217	
Ko	1.6		1.8	0.063		0.071	
Ро	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



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